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# PASSIVITY BREAKDOWN OF TITANIUM IN LiBr SOLUTIONS

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The passive behavior of titanium and its susceptibility to undergo localized attacks in different LiBr solutions at 25° C have been investigated using different electrochemical techniques: potentiodynamic polarization curves, potentiostatic passivation tests, EIS measurements and Mott-Schottky analysis. In low and moderately concentrated LiBr solutions, the breakdown potential  $E_b$  decreased with increasing bromide concentrations, while in highly concentrated LiBr solutions,  $E_b$  increased with increasing LiBr concentration. In the most concentrated LiBr solution (11.42M) Ti did not undergo passivity breakdown even at 9 V<sub>Ag/AgCl</sub>. These results have been related to a decrease in the activity of water in highly concentrated LiBr solutions.

**Keywords:** titanium; passivity breakdown; bromide solutions; activity of water; point defect model.

26 **1. INTRODUCTION**

27

28 Titanium is a very reactive metal that shows remarkable corrosion resistance in many  
29 environments due to the formation of a very stable, continuous, highly adherent, and  
30 protective passive oxide film on the metal surface. A freshly abraded titanium surface  
31 immediately passivates when exposed to an oxygen source (air and/or moisture). The  
32 nature, composition, and thickness of the passive film that forms on titanium depend on  
33 the environmental conditions. In most aqueous environments, the oxide is typically  
34  $\text{TiO}_2$ , but may consist of mixtures of other titanium oxides, including  $\text{TiO}_2$ ,  $\text{Ti}_2\text{O}_3$ , and  
35  $\text{TiO}$  [1-8]. The oxygen content of the titanium oxide gradually decreases from  $\text{TiO}_2$  at  
36 the surface, to  $\text{Ti}_2\text{O}_3$  and  $\text{TiO}$  as it approaches the metal/oxide interface [1]. Depending  
37 on the environment, this oxide may be covered with an amorphous or hydrated surface  
38 oxide, giving a two-layer oxide structure [1, 4, 5, 9]. The  $\text{TiO}_2$  passive film is an n-type  
39 semiconductor and its semiconductive properties determine the current/potential  
40 behavior of the titanium/passive film/electrolyte system [1, 6, 10-13]. The metal/passive  
41 film interface has been assumed to be an ohmic contact with minimal resistance. On the  
42 other hand, a space charge region has been hypothesized to develop at the passive  
43 film/electrolyte interface [6]. Oxygen vacancies have been reported to be the main  
44 defects within the passive film on titanium [13-15].  $\text{Ti}^{3+}$  interstitials have also been cited  
45 as electron donor species [10, 12].

46

47 Titanium exhibits excellent resistance to most salt solutions over a wide range of pH  
48 and temperatures [16]. Although titanium is resistant to these media, it is not immune  
49 and can be susceptible to pitting and crevice attack, depending on the environmental  
50 conditions [15-18]. Breakdown potentials ( $E_b$ ) of titanium in sulfate and phosphate

51 media are typically in excess of 80 V<sub>SCE</sub> [1, 19]. Values of 5 to 12 V<sub>SCE</sub> can be expected  
52 in room-temperature chloride solutions [1, 15, 18, 19]. However, it has been observed in  
53 numerous works that bromide anions are far more effective than chlorides or iodides in  
54 facilitating breakdown of the passive film formed on Ti [15, 17-22]. In fact, many  
55 authors have observed passivity breakdown of titanium in bromide containing solutions  
56 taking place at relatively low potentials compared to those in chloride or iodide  
57 containing solutions ( $E_b < 2-5 V_{SCE}$ ) [15, 17-24]. Sazou et al. [15] interpreted this high  
58 susceptibility of TiO<sub>2</sub> to local breakdown in the presence of bromides by considering  
59 electrochemical reactions taking place at the passive film/electrolyte interface, such as  
60 the formation of surface titanium peroxo-species, leading to changes in the surface and  
61 bulk properties (ionic and electronic) of the titanium oxide. The breakdown potential of  
62 titanium in relatively low concentrated bromide solutions (up to 1M) has been found to  
63 decrease with increasing bromide concentrations [15, 18, 20], with values in the range  
64 of 2-5 V<sub>Ag/AgCl</sub>. Nevertheless, it has been observed in recent works [2, 25] that in very  
65 concentrated LiBr solutions (700, 850 and 992 g/l LiBr, 8.06M, 9.78M and 11.42,  
66 respectively), titanium did not undergo localized attacks at potentials as high as  
67 3V<sub>Ag/AgCl</sub>. These results contradict the tendencies found in the literature for  $E_b$  with  
68 bromide concentration, since in heavy brine LiBr solutions the values of  $E_b$  should be  
69 lower than 2-3 V<sub>Ag/AgCl</sub>.

70

71 The aim of the present work is to study the influence of bromide concentration on the  
72 passivity breakdown of titanium at 25° C and to clarify the anomalous behavior of  
73 passive films formed on titanium in highly concentrated LiBr solutions against localized  
74 attacks. These heavy brine LiBr solutions are widely used in absorption cooling systems  
75 [26-30]. The steady-state properties of the passive film formed on Ti electrodes in

76 different LiBr solutions have been studied in this work, as well as the role of electronic  
77 properties and the activity of water on the stability of Ti passive film.

78

## 79 **2. MATERIALS AND METHODS**

80

### 81 *Materials, solution and electrochemical cell*

82

83 The material tested was commercially pure Grade 2 titanium (0.03 wt.% N, 0.1 wt.% C,  
84 0.25 wt.% O, 0.3 wt.% Fe, 0.0125 wt.% H, Bal. Ti). Titanium electrodes were  
85 cylindrically shaped and covered with a polytetrafluoroethylene (PTFE) coating, to  
86 expose an area of 0.5 cm<sup>2</sup> to the test solution. All specimens were wet abraded from 200  
87 to 4000 SiC grit, and finally rinsed with distilled water and air-dried. Titanium  
88 electrodes were tested in different LiBr solutions, from 0.05M to 11.42M, at a constant  
89 temperature of 25° C (**Table 1**). Values of molalities ( $m_{LiBr}$ ), mean ionic activity  
90 coefficients ( $\gamma_{\pm}$ ), activities of LiBr solutions ( $a_{LiBr}$ ), osmotic coefficients ( $\phi$ ) and  
91 activities of water ( $a_W$ ) are also shown in **Table 1**. Activities for LiBr solutions,  $a_{LiBr}$ ,  
92 have been calculated from the following equation:

93

$$94 \quad a_{LiBr} = \frac{m_{LiBr}}{m^0} \gamma_{\pm} \quad (1)$$

95

96 where the LiBr molality,  $m_{LiBr}$ , is defined as mol LiBr/kg H<sub>2</sub>O and  $m^0$  is the standard  
97 LiBr molality ( $m^0 = 1$  mol LiBr/kg H<sub>2</sub>O). Activity coefficients and osmotic coefficients  
98 have been obtained from the literature [31]. Activities of water have been calculated  
99 from osmotic coefficients according to the following expression [32, 33]:

100

101 
$$\ln(a_w) = -\phi M_w \nu m \quad (2)$$

102

103 where  $M_w$  is the molar mass of water and  $\nu$  is the stoichiometric parameter, i.e., the  
104 number of ion moles produced by complete dissociation of one mole of salt (for a 1:1  
105 salt such as LiBr,  $\nu$  equals 2); notice that molality  $m$  is expressed in kilomole of solute  
106 per kilogram of solvent (or mole of solute per gram of solvent) so the units in eq. (2) are  
107 consistent.

108

109 To study the effect of solvent nature and the influence of the bromide salt on the  
110 passivity breakdown of Ti, additional experiments were carried out in different  
111 electrolytes: 0.5M LiBr solutions with different water-methanol proportions (70 mol%,  
112 50 mol% and 0 mol% water), and a 3M KBr solution.

113

114 The electrochemical tests were performed in a sheathed vertical electrochemical cell. A  
115 silver-silver chloride (Ag/AgCl 3M KCl) was used as reference electrode and a  
116 platinum wire as auxiliary electrode. Electrochemical measurements were performed  
117 using an Autolab PGSTAT302N potentiostat. In all cases the tests were repeated at least  
118 three times in order to verify reproducibility.

119

120 *Potentiodynamic polarization curves*

121

122 Polarization tests began at a cathodic potential value of  $-0.9 \text{ V}_{\text{Ag/AgCl}}$  and the potential  
123 was subsequently scanned anodically at a scan rate of  $0.5 \text{ mV s}^{-1}$ . The passive current  
124 density,  $i_p$ , and the breakdown potential,  $E_b$  (defined as the potential at which the current  
125 density increases abruptly after the peak corresponding to the  $\text{Br}^-/\text{Br}_2$  oxidation), were

126 obtained from potentiodynamic polarization tests. After potentiodynamic polarization,  
127 the morphological inspection of the Ti electrodes surface was done using a Leica DM  
128 LA optical microscope.

129

### 130 *Potentiostatic passivation tests*

131

132 Before the potentiostatic passivation experiments, the surface of the Ti electrodes was  
133 pretreated cathodically at  $-0.9 V_{\text{Ag/AgCl}}$  for 30 min to create reproducible initial  
134 conditions. Afterwards, the working electrode was polarized at a potential within the  
135 passive region of titanium ( $0.4 V_{\text{Ag/AgCl}}$ ) for 1 hour in several LiBr solutions (0.1M,  
136 0.5M, 3M and 11.42M) at  $25^\circ \text{C}$ , to form a stable passive film. During passivation  
137 experiments, transients in the current density were recorded against time.

138

### 139 *EIS and capacitance measurements*

140

141 EIS and capacitance measurements were performed under potentiostatic conditions after  
142 the passivation tests, once a stable passive film was formed on the surface of the Ti  
143 samples. EIS measurements were conducted using a sinusoidal signal of 10 mV in  
144 amplitude in the frequency range of 100 kHz-10 mHz. Capacitance measurements were  
145 performed at a frequency of 10 kHz applying a sinusoidal potential perturbation of 10  
146 mV and scanning the potential from the formation value in the negative direction at a  
147 rate of  $25 \text{ mV s}^{-1}$ .

148

## 149 **3. RESULTS AND DISCUSSION**

150

151 **Potentiodynamic polarization curves**

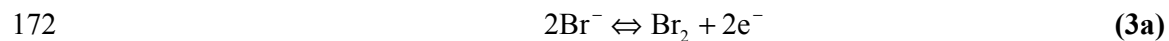
152

153 The potentiodynamic polarization curves obtained for Ti in different LiBr solutions at  
154 25° C are shown in **Figure 1**. A wide passive range can be observed in all LiBr  
155 solutions where passive current density values ( $i_p$ ) remain very low (of the order of 1-3  
156  $\mu\text{A cm}^{-2}$ ), indicating the excellent passive behavior of Ti (**Table 2**). The values of  $i_p$   
157 have been estimated at a potential of 0.4 V, within the stable passive region. At first,  $i_p$   
158 slightly increases with increasing LiBr concentrations, but at concentrations higher than  
159 0.7 M it starts decreasing until reaching its lowest value ( $1 \mu\text{A cm}^{-2}$ ) in the 11.42 LiBr  
160 solution.

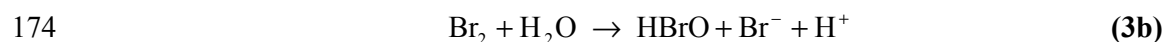
161

162 Upon increasing the anodic polarization of Ti, the occurrence of a broad anodic wave  
163 can be observed at potentials between 1-1.5 V, corresponding to the oxidation of  
164 bromides present in the solution ( $E^0(\text{Br}_2/\text{Br}^-) = 0.89 \text{ V}_{\text{Ag}/\text{AgCl}}$ ). This anodic wave is more  
165 evident at high LiBr concentrations. In fact, in the potential range between 1-1.5 V a  
166 change of the solution color around the titanium electrode surface (from colorless to  
167 yellow-orange) was noticeable at high LiBr concentrations. This change in color is  
168 related to the localized oxidation of bromide ions to bromine ( $\text{Br}_2$ ) at electroactive sites  
169 at potentials around  $1.5 \text{ V}_{\text{Ag}/\text{AgCl}}$  [15, 17-20, 22] and to the subsequent formation of  
170  $\text{HBrO}$ , according to the following equations [34]:

171



173



175



176 Apart from the oxidation of  $\text{Br}^-$ , several processes may take place simultaneously during  
177 anodic polarization of titanium at high potentials, such as oxygen evolution reaction  
178 (OER) [2, 19, 21, 23, 25, 35], oxidation of  $\text{TiO}$  and  $\text{Ti}_2\text{O}_3$  to  $\text{TiO}_2$  [2, 3, 5, 25, 35] or  
179 additional oxidation of  $\text{TiO}_2$  to form soluble complex species, such as  $\text{TiO}^{2+}$  [36],  
180 or/and peroxy-species, such as  $\text{TiO}_3$  or  $\text{TiOOH}$  [7, 8, 10, 15].

181

182 The abrupt increase of current density at potentials above the  $\text{Br}^-$  oxidation peak  
183 indicates the onset of passivity breakdown of Ti. Once exposed to the  $\text{Br}^-$  solution, the  
184 Ti metal rapidly oxidizes to a soluble oxi-halide  $\text{Ti}^{4+}$  species [18, 23]. In the low and  
185 moderately concentrated LiBr solutions (**Figure 1a**) a decrease of  $E_b$  with increasing  
186 bromide concentration can be observed, as reported in the literature [15, 18, 20] (**Table**  
187 **2**). In the more concentrated LiBr solutions (**Figure 1b**), on the other hand,  $E_b$  does not  
188 follow the previous tendency, since its value increases with increasing LiBr  
189 concentration (**Table 2**). In fact, in the 11.42M LiBr solution Ti did not undergo  
190 localized attacks under the experimental conditions (up to  $9 \text{ V}_{\text{Ag}/\text{AgCl}}$ ), indicating that  $E_b$   
191 is apparently higher than  $9 \text{ V}_{\text{Ag}/\text{AgCl}}$ , which is a behavior more typical of chloride- or  
192 iodide- than bromide-containing solutions [18]. A similar behavior was observed by  
193 Davydov for niobium in LiBr solutions [37]. By way of illustration, **Figure 2** shows the  
194 images of the Ti electrode surface before and after the polarization tests in 0.5M  
195 (**Figure 2a**) and 11.42M (**Figure 2b**) LiBr solution. Visual inspection of the Ti  
196 electrode polarized in the 0.5M LiBr solution (**Figure 2a**) reveals the presence of  
197 several large corrosion pits. On the other hand, no damage is observed on the Ti  
198 electrode polarized in the 11.42M LiBr solution up to 9 V (**Figure 2b**), in accordance  
199 with the description of the polarization curves made above.

200

201 **Figure 3** shows the plot of  $E_b$  vs. the logarithm of bromide activity ( $\log a_{Br^-}$ ) for all the  
 202 LiBr solutions under study. It can be observed that  $E_b$  decreases linearly with  $\log a_{Br^-}$   
 203 for the low and moderately concentrated LiBr solutions, while it increases linearly with  
 204  $\log a_{Br^-}$  for the highly concentrated LiBr solutions (except in the 11.42M LiBr solution,  
 205 where passivity breakdown was not observed at all under the experimental conditions,  
 206 as commented above). The linear relationship with negative slope between  $E_b$  and  $\log$   
 207  $a_{Br^-}$  (in low and moderately concentrated LiBr solutions) has been predicted analytically  
 208 by the Point Defect Model (PDM) [38, 39], according to the following equation:

209

$$210 \quad E_b = \left( \frac{4.606RT}{\chi\alpha F} \right) \log\left(\frac{b}{D}\right) - \frac{2.303RT}{\alpha F} \log(a_{Br^-}) \quad (4)$$

211

212 where  $\chi$  is the charge of the metal ions ( $Ti^{4+}$ ),  $\alpha$  is the polarizability of the passive  
 213 film/solution interface,  $F$  is Faraday's constant ( $96485.34 \text{ C mol}^{-1}$ ),  $b$  is a constant,  $D$  is  
 214 the diffusivity of cation vacancies in the passive film,  $R$  is the gas constant and  $T$  is  
 215 absolute temperature. From the straight line with negative slope shown in **Figure 3**, the  
 216 value of  $\alpha$  can be determined, yielding a value of 0.045. This low value is comparable to  
 217 those reported in the literature for Ti [13, 15]. A low value of  $\alpha$  suggests that the  
 218 Helmholtz layer is very weakly polarized since the potential drop at the passive  
 219 film/solution interface is negligible. Thus, almost all the potential drop in the interfacial  
 220 regions takes place in the metal/passive film interface, where the reaction of passive  
 221 film formation and growth occurs according to the PDM [40-42].

222

### 223 **Potentiostatic passivation tests**

224

225 The current density transients obtained after applying a potential step from a value of  
 226 -0.9 V (cathodic pre-treatment) to a value of 0.4 V within the passive region are shown  
 227 in **Figure 4** for different LiBr solutions (0.1M, 0.5M, 3M and 11.42M). It can be  
 228 observed that current densities follow the same tendency as  $i_p$ , that is, the order from  
 229 highest to lowest values during the whole potentiostatic test is: 0.5M, 3M, 0.1M and  
 230 11.43 LiBr solutions. In all cases, current density values decrease exponentially with  
 231 passivation, and eventually reach a steady-state value ( $i_{SS}$ ). These values are the  
 232 following:  $0.12 \pm 0.05 \mu\text{A cm}^{-2}$  (0.1M),  $0.22 \pm 0.07 \mu\text{A cm}^{-2}$  (0.5M),  $0.17 \pm 0.05 \mu\text{A cm}^{-2}$   
 233 (3M) and  $0.059 \pm 0.03 \mu\text{A cm}^{-2}$  (11.42M). Virtanen and Curty [20] observed a clear  
 234 increase in passive current density with increasing bromide concentrations for Ti in  
 235 NaBr. However, in the present study,  $i_{SS}$  increases with  $\text{Br}^-$  concentration at relatively  
 236 low concentrations, but it decreases with concentration at high LiBr concentrations.

237

238 According to the PDM [42-44], the steady-state current density can be written as:

239

$$240 \quad i_{SS} = \delta F \left[ k_{int} + k_{cat} + k_{dis} \left( \frac{C_{H^+}}{C_{H^+}^0} \right)^n \right] \quad (5)$$

241

242 where  $\delta$  is the charge of the cation ejected from the passive film (3 in the case of  $\text{Cr}^{3+}$ ),  
 243  $C_{H^+}$  is the proton concentration in the solution,  $C_{H^+}^0$  is a standard state  $H^+$  concentration  
 244 and  $n$  is the kinetic order of the reaction of passive film dissolution with respect to  
 245  $(C_{H^+} / C_{H^+}^0)$ . The parameters  $k_{int}$ ,  $k_{cat}$  and  $k_{dis}$  are the rate coefficients for the reactions of  
 246 formation of cation interstitials, cation vacancies and of passive film dissolution,  
 247 respectively. Eq. (5) suggests that the steady-state current density  $i_{SS}$  is associated with  
 248 the fluxes of point defects and also with the kinetic parameters for the interfacial

249 reactions. Hence,  $i_{SS}$  consists of three components: the first ( $\delta Fk_{int}$ ) resulting from the  
250 generation and transport of cation interstitials, the second ( $\delta Fk_{cat}$ ) resulting from the  
251 generation and transport of cation vacancies and the third  $\delta Fk_{dis} \left( C_{H^+} / C_{H^+}^0 \right)^n$  resulting  
252 from the movement of oxygen vacancies. The latter term is expressed in terms of the  
253 dissolution rate of the passive film [42-45].

254

255 The passive film on titanium is well known to behave as an *n*-type semiconductor [1, 6,  
256 10-13] (see Mott-Schottky analysis below), whose donor species are oxygen vacancies  
257 and/or  $Ti^{3+}$  interstitials [10, 12-15], so the term related to the generation and transport of  
258 cation vacancies,  $k_{cat}$ , can be neglected [43]. Therefore, the differences between current  
259 densities with LiBr concentration are either due to the process of generation and  
260 transport of cation interstitials or the dissolution of the passive film closely related to  
261 the generation and movement of oxygen vacancies in the steady-state [41].

262

263

#### 264 **Mott-Schottky analysis**

265

266

267

268 In order to check if the differences observed in  $i_{SS}$  at different LiBr concentrations is  
269 due to the generation of donor species at the metal/passive film interface (oxygen  
270 vacancies and/or cation interstitials), the electrochemical capacitance of the passive  
271 system was measured as a function of the applied potential. Mott-Schottky (M-S)  
272 analysis was performed to obtain the donor density,  $N_D$ , of the passive films formed on  
273 Ti in different LiBr solutions. The total capacitance has been calculated from the  
274 imaginary component of the impedance ( $Z''$ ) using the relationship  $C = -1/\omega Z''$ , where  $\omega$   
275 is the angular frequency.

276

277 As an illustration, **Figure 5** shows the capacitance-potential curves obtained for Ti in  
278 the 0.5M LiBr solution at 0.4 V and at different frequencies. It is clearly observed that  
279 capacitance values depend strongly on frequency. Capacitance-potential curves shift to  
280 lower values with increasing frequencies. Such behavior has been frequently observed  
281 for semiconducting passive films formed on metals and alloys [12, 46-54]. Several  
282 physical explanations have been suggested in the literature as possible sources of this  
283 dependence [46-54], such as the presence of deep donor states, contribution of surface  
284 states, surface roughness, ionic charges movement, frequency dependant dielectric  
285 constant, etc. It can be seen from **Figure 5** that capacitance becomes almost  
286 independent of frequency at approximately 10 kHz. Therefore, a value of 10 kHz has  
287 been used in this work to eliminate capacitance dependence on frequency.

288

289 **Figure 6** shows the Mott-Schottky plots at a frequency of 10 kHz of the passive film  
290 formed on Ti in 0.1M, 0.5M, 3M and 11.42M LiBr solutions at 0.4 V. The positive  
291 slopes of the M-S plots are characteristic of *n*-type semiconductors, with the dominant  
292 defects in the passive film being oxygen vacancies and/or Ti<sup>3+</sup> interstitials, as it has  
293 been mentioned above.

294

295 The donor density,  $N_D$ , can be determined from the slopes in the M-S plots, according to  
296 the following equation [10, 12]:

297

$$298 \quad N_D = \frac{2}{\epsilon\epsilon_0 e\sigma} \quad (6)$$

299

300 where  $\epsilon$  is the dielectric constant of the passive film (a value of 60 has been assumed for  
301 the passive film formed on Ti [15]),  $\epsilon_0$  is the vacuum permittivity ( $8.85 \cdot 10^{-14}$  F/cm),  $e$  is

302 the electron charge ( $1.60 \cdot 10^{-19}$  C) and  $\sigma$  is the positive slope of each straight line in the  
303 M-S plots.

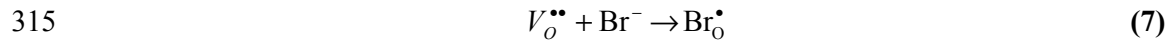
304

305 The values of  $N_D$  are presented in **Figure 7** for different LiBr solutions (0.1M, 0.5M,  
306 3M and 11.42M) at 0.4 V. The results show that  $N_D$  values are of the order of  $10^{19}$ - $10^{20}$   
307  $\text{cm}^{-3}$ , regardless the LiBr concentration, which is in agreement with those reported in the  
308 literature for  $\text{TiO}_2$  [10, 12].

309

310 An increase in LiBr concentration from 0.1M to 0.5M leads to a clear increase of  $N_D$   
311 (**Figure 7**). The PDM [38, 40, 55] assumes that the initial event that takes place at the  
312 passive film/electrolyte interface in passivity breakdown is the occupation of surface  
313 oxygen vacancies by aggressive anions, such as bromides:

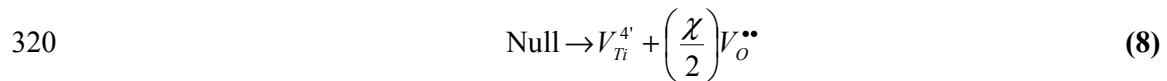
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316

317 where  $\text{Br}_{\text{O}}^{\bullet}$  represents a bromide anion adsorbed into an oxygen vacancy,  $V_{\text{O}}^{\bullet\bullet}$ , in the  
318 film/electrolyte interface. This process is followed by a Schottky-pair type reaction:

319



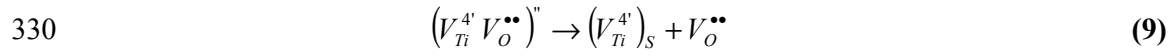
321

322 where  $V_{\text{Ti}}^{4+}$  is a cation vacancy in the Ti passive film. Kroger-Vink notation is used for  
323 the effective positive ( $\bullet\bullet$ ) and negative ( $4+$ ) charges in oxygen and cation vacancies,  
324 respectively.

325

326 The adsorbed  $\text{Br}^-$  anions could desorb along with a surface cation to form a cation  
 327 vacancy/oxygen vacancy pair  $(V_{\text{Ti}}^{4+} V_{\text{O}}^{\bullet\bullet})^2$ . This pair is subsequently annihilated, leading  
 328 to the formation of a subsurface cation vacancy and the regeneration of the surface  $V_{\text{O}}^{\bullet\bullet}$  :

329



331

332 where the subscript  $S$  indicates a subsurface position in the passive film. The oxygen  
 333 vacancies continue reacting with additional  $\text{Br}^-$  at the film/electrolyte interface to  
 334 generate additional cation and oxygen vacancies. Hence, the generation of cation and  
 335 oxygen vacancies through eqs. (7)-(9) is autocatalytic.

336

337 Anion adsorption leads to the generation of cation vacancies at the film/solution  
 338 interface and hence to an enhancement in the flux of cation vacancies across the passive  
 339 film to the film/metal interface due to the outward movement (towards the passive  
 340 film/electrolyte interface) of cations in the film. If the flux of cation vacancies exceeds  
 341 the rate at which they are annihilated at the metal/film interface, the excess vacancies  
 342 will condense at the interface and the passive film will be locally detached from the  
 343 metal. As passive film dissolution continues, the film thins locally, eventually leading to  
 344 film breakdown [40].

345

346 According to the previous explanation, since oxygen vacancies are donor species, the  
 347 higher the donor density in the passive film,  $N_D$ , the lower the resistance to passivity  
 348 breakdown. This affirmation is in agreement with the values of the breakdown potential,  
 349  $E_b$ , shown in **Table 2**, where  $E_{b0.5M} < E_{b0.1M}$ . However, when increasing the LiBr  
 350 concentration from 0.5M to 3M and 11.42M,  $N_D$  decreases, indicating that the higher

351 bromide concentration in the 3M and 11.42M LiBr solutions does not lead to a higher  
352 degree of oxygen vacancies occupation by bromide ions. This result could explain the  
353 lower susceptibility of Ti to undergo passivity breakdown in the 3M and 11.42M LiBr  
354 solutions if compared with the 0.5M LiBr solution. Nevertheless, since the  $N_D$  values  
355 obtained in concentrated LiBr solutions are still higher than that in the 0.1M LiBr  
356 solution, this fact cannot satisfactorily explain the increase of  $E_b$  at high LiBr  
357 concentrations or even the absence of passivity breakdown in the 11.42M LiBr solution.

358

359 The tendency of  $N_D$  with LiBr concentration also confirms that the differences  
360 mentioned above in the steady-state current density ( $i_{SS}$ ) with LiBr concentration are not  
361 related to the density of donor species (oxygen vacancies and/or cation interstitials),  
362 since  $i_{SS0.1M} > i_{SS11.42M}$  but  $N_{D0.1M} < N_{D11.42M}$ .

363

#### 364 **EIS measurements**

365

366 Mott-Schottky analysis has proved that the behavior of the passive film on Ti against  
367 localized attacks in high LiBr concentrations is not directly related with its electronic  
368 properties. **Figure 8** shows the experimental and simulated Nyquist diagrams for Ti in  
369 0.1M, 0.5M, 3M and 11.42M LiBr solutions at 0.4 V. The experimental data have been  
370 fitted to the electrical equivalent circuit shown in **Figure 9**, commonly used to account  
371 for the bilayer structure of the passive film on Ti (porous outer layer and compact inner  
372 layer) [4, 5, 56]

373



374 In all cases, Nyquist plots exhibit a typical passive state behavior characterized by  
375 semicircular shape and high impedance values, suggesting that a highly stable film is  
376 formed on all the electrodes [31-34].

377

378 An increase in LiBr concentration from 0.1M to 0.5M reduces the amplitude of the  
379 semicircle in Nyquist plots, indicating a decrease of the total impedance of the system  
380 and a loss in the protective properties of the passive film. This result is consistent with  
381 the higher  $i_{SS}$  and  $N_D$  values obtained in the 0.5M LiBr solution. However, upon  
382 increasing the bromide concentration to 3M and 11.42M, the total impedance increases  
383 again, which agrees with the tendency of  $i_{SS}$  observed before (the lower the  $i_{SS}$ , the  
384 higher the total impedance of the system), but differs in the case of  $N_D$  values (**Figure**  
385 **7**), since the lowest  $N_D$  value (0.1M LiBr solution) does not imply the highest  
386 impedance values.

387

388 The values of the equivalent circuit parameters are shown in **Table 3**. In this equivalent  
389 circuit,  $R_S$  represents the solution resistance, the time constant at high frequencies  
390 ( $R_1CPE_1$ ) is related to the outer layer of the passive film (hydroxides), whereas the low-  
391 frequency behavior ( $R_2CPE_2$ ) is attributed to the inner layer (mainly TiO<sub>2</sub>), more  
392 compact than the outer one. Constant Phase Elements (CPEs) have been used instead of  
393 pure capacitors, to describe the non-ideality of the system studied. CPEs have been  
394 converted into pure capacitance,  $C$ , by using the following equation [57, 58]:

395

$$396 \quad C = \frac{(Q \cdot R)^{1/\alpha}}{R} \quad (10)$$

397

398 where  $Q$  is the impedance of the CPE and  $R$  corresponds to  $R_2$  when determining  
399 capacitance values of the second time constant in **Figure 9**. To determine  $C_1$  from  
400  $CPE_1$ ,  $R$  has been calculated as follows:

401

$$402 \quad \frac{1}{R} = \frac{1}{R_s} + \frac{1}{R_1} \quad (11)$$

403

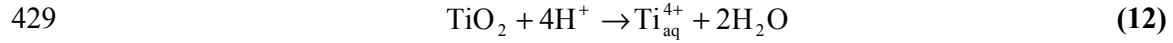
404 It can be observed from **Table 3** that the resistance values of the compact inner layer  
405 ( $R_2$ ) are significantly larger than the values associated with the outer porous layer ( $R_1$ ),  
406 which is consistent with the chosen physical model. These results indicate that the  
407 protection provided by the passive film is predominantly due to the barrier layer. In  
408 general, both the outer and inner layers exhibit similar capacitance values, of the order  
409 of some  $\mu\text{F cm}^{-2}$ . Regarding the influence of LiBr concentration on the parameters, it  
410 can be observed that  $R_1$  decreases at high LiBr concentrations, while  $R_2$  decreases from  
411 0.1M to 0.5M but then it increases again, reaching the highest value in the 11.42M LiBr  
412 solution. These results are in agreement with those obtained for  $i_{SS}$  (the lower the value  
413 of  $i_{SS}$ , the higher the resistance of the barrier inner layer of the passive film,  $R_2$ ).

414

415 According to the M-S results, the increase of  $R_2$  in the 3M and 11.42M LiBr solutions  
416 with respect to the value in the 0.1M LiBr solution cannot be related to the degree of  
417 defectiveness of the passive film on Ti (**Figure 7 and Table 3**). This increase of  $R_2$   
418 could be explained in terms of the passive film dissolution and the influence of the  
419 activity of water,  $a_w$ , on this process. Water is one of the reacting species in  
420 electrochemical and corrosion mechanisms, but most corrosion works focus on the  
421 properties of solutes whereas changes in the activity of water are rarely considered [33,  
422 59]. Smart and Bockris [59] observed a decrease in the corrosion current density of iron  
423 in concentrated chloride media with decreasing free water in the solution, that is, the

424 rate of iron dissolution ( $\text{Fe}/\text{Fe}^{2+}$ ) was shown to strongly decrease with decreasing  
425 activity of water. Hence, in the case of Ti in highly concentrated LiBr solution, the  
426 decrease of  $a_W$  (**Table 1**) might lead to similar results. **The reaction of dissolution of the**  
427 **passive film formed on Ti by proton attack can be expressed as follows:**

428



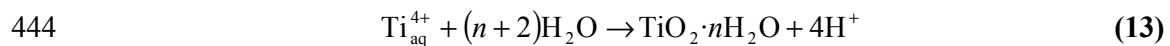
430

431 Although the activity of protons,  $a_{\text{H}^+}$ , is constant, the concentration of  $\text{H}^+$  will decrease  
432 with decreasing free water (decreasing  $a_W$ ). Therefore, the dissolution reaction given by  
433 eq. (12) not only depends on pH ( $a_{\text{H}^+}$ ) but also on the number on  $\text{H}^+$  at the passive  
434 film/electrolyte interface, which in turn depends on  $a_W$ . **Passive film dissolution is a**  
435 **necessary step for passivity breakdown to occur, causing the thinning and subsequent**  
436 **rupture of the passive film** [40, 60]. Therefore, if passive film dissolution is somehow  
437 hampered, for example by reducing the activity of water, passivity breakdown will  
438 appear at higher potentials. This fact would explain the increase of  $E_b$  in highly  
439 concentrated LiBr solutions (**Table 2**).

440

441 On the other hand, the formation of the precipitated outer layer ( $\text{TiO}_2 \cdot n\text{H}_2\text{O}$ ) via the  
442 hydrolysis of  $\text{Ti}^{4+}$  cations ejected from the inner layer (eq. (12)) also depends on  $a_W$ :

443

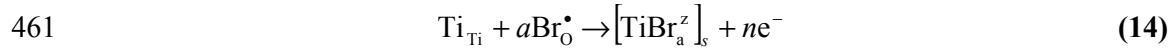


445

446 In fact, the values of the outer layer resistance,  $R_l$ , are higher in the 0.1M and 0.5M  
447 LiBr solutions (**Figure 7**), indicating that the formation of precipitated hydroxides is  
448 favored when  $a_W$  values are close to unity (**Table 1**).

449 However, the explanations given above concerning the dissolution of the passive film  
 450 do not completely explain why this behavior has not been observed, for example, in  
 451 stainless steels in highly concentrated LiBr solutions [35, 61, 62]. Apart from the  
 452 process of passive film dissolution (eq. (12)), there must be other Ti-specific surface  
 453 processes which are influenced by the decrease of  $a_w$  in highly concentrated LiBr  
 454 solutions. Davydov [37] suggested that the formation of an intermediate complex  
 455 between a valve metal (such as Ti) and the aggressive anions ( $\text{Br}^-$ ) and its interaction  
 456 with the metal oxide could restrict the process of metal dissolution. Following the  
 457 descriptions of Davydov [37], this complex is formed when a bromide anion adsorbs on  
 458 a surface oxygen vacancy (eq. (7)) and then interacts with a Ti cation in the passive film  
 459 ( $\text{Ti}_{\text{Ti}}$ ), according to the following reaction:

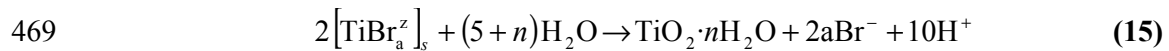
460



462

463 where  $z = n + a$  and  $[\text{TiBr}_a^z]_s$  is the surface complex. Along with the complex formation,  
 464 a cation vacancy/anion vacancy pair is also generated via a Schottky-pair type reaction,  
 465 eq. (8). The hydrolysis of the complex will break the bond with the passive film, thus  
 466 favoring the process of dissolution with the formation of the product of activated  
 467 dissolution,  $\text{TiO}_2 \cdot n\text{H}_2\text{O}$ :

468



470

471 As in the case of eq. (12), a decrease in the content of free water (i.e. decrease in  $a_w$ )  
 472 will slow down the process of hydrolysis and, as a consequence, the full process of  
 473 passivity breakdown.

474

475 **Influence of solvent and solute on the activity of water and passivity breakdown**

476

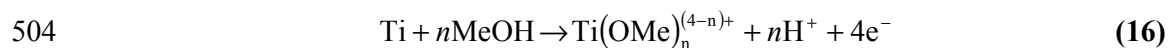
477 In order to verify that the decrease of the activity of water is responsible for the decrease  
478 of the susceptibility of Ti to undergo passivity breakdown in highly concentrated LiBr  
479 solutions, additional electrolytes have been used to study the electrochemical behavior  
480 of Ti. In the first case, the activity of water has been reduced by adding different  
481 amounts of methanol to a 0.5M LiBr aqueous solution.  $a_W$  values in these solutions have  
482 been estimated from literature [63] taking the values of  $a_W$  shown in **Table 1** as starting  
483 point: water-free methanol solution ( $a_W \approx 0$ ), 50 mol% water – 50 mol% methanol ( $a_W \approx$   
484 0.60) and 70 mol% water – 30 mol% methanol ( $a_W \approx 0.76$ ). In the second case, the  
485 activity of water has been increased by changing the bromide salt (LiBr was replaced by  
486 KBr), since Li is the smallest alkali cation and it is most strongly hydrated, thus  
487 reducing the amount of free water in the solution. A 3M KBr solution has been used,  
488 whose molality  $m_{KBr} = 3.40 \text{ (mol KBr) (kg H}_2\text{O)}^{-1}$  is similar to that of a 3M LiBr  
489 solution ( $m_{LiBr} = 3.77 \text{ (mol LiBr) (kg H}_2\text{O)}^{-1}$ ). The comparison of mean ionic activity  
490 coefficients ( $\gamma_{\pm}$ ) and activities of water ( $a_W$ ) between LiBr and KBr solutions is shown  
491 in **Figures 10a** and **10b**, respectively. It can be observed that  $\gamma_{\pm}$  values are higher in  
492 LiBr solutions than in KBr solutions in almost the whole range of molalities, while  $a_W$   
493 values are visibly lower for LiBr solutions than for KBr solutions at molalities higher  
494 than  $2 \text{ mol kg}^{-1}$  (for 3M KBr and LiBr solutions,  $a_{W\_KBr} = 0.89$  and  $a_{W\_LiBr} = 0.81$ ).

495

496 **Figure 11** shows the potentiodynamic polarization curves of Ti in a 0.5M LiBr solution  
497 with different water-methanol mol%. It can be observed that the four curves present a  
498 clear passive range, regardless the water and methanol content. However, in the water-

499 free methanol solution, this passive range is significantly narrower than in the other  
500 solutions. Burstein and Whillock [64], as well as Banas et al [65], studied the passive  
501 behavior of Ti and other metals in methanolic solutions, and they concluded that  
502 methanol was responsible for the process of Ti dissolution, according to:

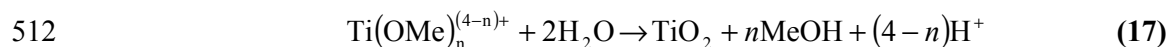
503



505

506 In the presence of water, (50 mol% water, 70 mol% water and aqueous solution), Ti  
507 presents considerably wider passive regions than in the free-water methanol solution  
508 (**Figure 11**). Apart from the formation of  $\text{TiO}_2$  due to direct reaction of Ti with water  
509 molecules, the dissolved complex of Ti(IV) formed according to eq. (16) could  
510 hydrolyze to form additional  $\text{TiO}_2$  [64]:

511



513

514 It is clearly observed in **Figure 11** that the breakdown potential in the water-methanol  
515 mixed solutions is significantly higher than in the aqueous solution ( $E_{b70\_30} = 4.9 \pm 0.2$  V;  
516  $E_{b50\_50} = 3.7 \pm 0.3$  V;  $E_{b\_aqueous} = 2.6 \pm 0.2$  V). This increase in  $E_b$  can be explained taking  
517 into account the decrease of free water in the electrolyte (i.e. decrease in  $a_w$ ), by  
518 partially replacing the aqueous solvent by the methanolic one. Thus, although methanol  
519 causes Ti dissolution (eq. (16)), the decrease of  $a_w$  slows down the dissolution of the  
520 electrode surface via eqs. (12) and/or (15), in a similar way as in highly concentrated  
521 LiBr solutions.

522

523 The potentiodynamic polarization curves of Ti in 3M KBr and 3M LiBr solutions are  
524 presented in **Figure 12**. It can be observed that Ti is more susceptible to undergo  
525 passivity breakdown in the 3M KBr solution ( $E_{b\_KBr} = 2.6 \pm 0.2$  V) than in the 3M LiBr  
526 solution ( $E_{b\_LiBr} = 3.3 \pm 0.3$  V). As it has been explained before, the mean ionic activity  
527 coefficient reaches higher values in LiBr than in KBr solutions due to the high charge  
528 density of the small lithium ion (**Figure 10a**). The higher activity coefficients in LiBr  
529 solutions result in higher activity of bromide anions ( $a_{Br^-}$  in the 3M KBr solution is 2.0  
530 and  $a_{Br^-}$  in the 3M LiBr solution is 6.6). As stated in eq. (4), the value of  $E_b$  should be  
531 higher in the 3M KBr solution than in the 3M LiBr solution, since  $a_{Br^-}$  is significantly  
532 lower in the former electrolyte. However, the higher values of  $\gamma_{\pm}$  in the LiBr solutions  
533 indicate a very strong interaction between water and ions, which lead to a decrease of  
534  $a_w$  (**Figure 10b**). Again, the reduction of  $a_w$  in the 3M LiBr solution restricts the  
535 process of dissolution of the Ti surface (eqs. (12) and/or (15)), thus delaying the onset  
536 of stable passivity breakdown.

537

### 538 **Relationship between $E_b$ and $a_w$ in concentrated LiBr solutions**

539

540 The linear relationship with positive slope found between  $E_b$  and  $\log a_{Br^-}$  in highly  
541 concentrated LiBr solutions (**Figure 3**) provides an empirical equation to evaluate  $E_b$  in  
542 function of the activity of bromide anions. However, according to the previous results, it  
543 is more coherent to relate  $E_b$  to the activity of water,  $a_w$ , since it is this parameter that  
544 directly affects the value of  $E_b$  in these concentrated media. Starting from eqs. (1) and  
545 (2), the activity of water can be expressed in terms of  $a_{Br^-}$ :

546

$$\log a_w = \frac{-\phi M_w \nu \frac{a_{Br^-}}{\gamma_{\pm}}}{2.303 \cdot 1000} = \frac{-\phi \cdot 18 \cdot 2 \frac{a_{Br^-}}{\gamma_{\pm}}}{2.303 \cdot 1000} = \frac{-A\phi a_{Br^-}}{\gamma_{\pm}} \quad (18)$$

548

549 On the other hand,  $a_{Br^-}$  can be expressed in terms of  $E_b$  by using the linear relationship

550  $E_b$  vs.  $\log a_{Br^-}$  mentioned above (**Figure 3**):

551

$$a_{Br^-} = 10^{\frac{E_b - 2.50}{0.93}} \quad (19)$$

553

554 Substituting eq. (19) into eq. (18):

555

$$-\log a_w = \frac{A\phi}{\gamma_{\pm}} 10^{\frac{E_b - 2.50}{0.93}} \rightarrow \log(-\log(a_w)) = \log\left(\frac{A\phi}{\gamma_{\pm}}\right) + \left(\frac{E_b - 2.50}{0.93}\right)$$

557

558 Finally, solving for  $E_b$  yields:

559

$$E_b = 0.93 \cdot \left[ \log(-\log(a_w)) - \log\left(\frac{A\phi}{\gamma_{\pm}}\right) \right] + 2.50 \quad (20)$$

561

562 Eq. (20) relates the value of  $E_b$  to a logarithmic function of  $a_w$ . **Figure 13** shows the

563 experimental and calculated values of  $E_b$  as a function of  $a_w$  in concentrated LiBr

564 solutions. It can be observed that both experimental and calculated values of  $E_b$  are

565 similar, indicating that eq. (20) can be used to satisfactorily calculate the breakdown

566 potential of Ti in concentrated LiBr solutions ( $m_{LiBr} > \sim 0.7 \text{ mol kg}^{-1}$ ) as a function of

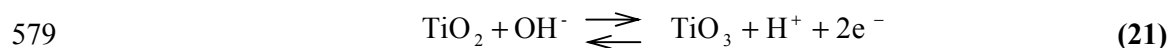
567 the activity of water.

568



569 Finally, it is necessary to explain why Ti did not undergo passivity breakdown in the  
570 11.42M LiBr solution. According to eq. (20), the breakdown potential of Ti in the  
571 11.42M LiBr solution ( $a_W = 0.12$ ) should be 5.6 V. However, passivity breakdown was  
572 not observed even at potentials as high as 9 V. The absence of localized attacks in this  
573 solution can be explained by changes in the TiO<sub>2</sub> surface. The irreversible formation of  
574 titanium peroxo species at sufficiently high potentials (normally higher than  $3V_{Ag/AgCl}$ )  
575 has been reported in the literature [7, 8, 15]. The formation of Ti peroxo species may  
576 result in a very thin insulating or dielectric layer [8, 15] which would form in the  
577 hydrated (outer) part of the passive film above 3V [8]:

578



580

581 The presence of these species, such as TiO<sub>3</sub>, can be noted by a yellowish color on the  
582 electrode surface [8]. This yellow color was observed on the undamaged areas of all the  
583 electrodes after the potentiodynamic polarization tests. However, the surface of the  
584 electrode polarized in the 11.42M LiBr solution had a dark golden color. The color-  
585 dependence of anodic Ti oxide layers on the polarization potential, and hence oxide  
586 thickness, is a very well known phenomenon [66-73]. For example, it has been observed  
587 [70, 71, 73] that at 5V the Ti surface has a light yellow color, while at 10-15V the  
588 surface color changes to dark golden/brown. Hence, the absence of stable localized  
589 attacks of Ti in the 11.42M LiBr solution can be attributed either to the formation of a  
590 highly insulating or dielectric layer of Ti peroxo species at potentials higher than ~5V  
591 (the value of  $E_p$  in the 8.06M LiBr solution is 4.7V) or/and to the increase of the Ti  
592 oxide film thickness. Both phenomena could block the interaction between aggressive  
593 anions and the surface of Ti, preventing passivity breakdown. This mechanism may be

594 similar to that reported by Sazou et al. [15] to explain passivity breakdown of Ti at high  
595 potentials in the presence of high concentrations of chlorides. In any case, it is evident  
596 that at sufficiently high potentials (higher than ~5V) the surface properties of the  
597 titanium oxide change to such an extent that the risk of passivity breakdown is  
598 completely eliminated, at least up to potentials as high as 9V.

599

## 600 **5. CONCLUSIONS**

601

602 A wide passive range where passive current density values ( $i_p$ ) remained very low (of  
603 the order of 1-3  $\mu\text{A cm}^{-2}$ ) was observed in all LiBr solutions, indicating the excellent  
604 passive behavior of Ti.  $i_p$  values slightly increased with increasing LiBr concentrations  
605 up to 0.7M LiBr, where  $i_p$  started to decrease until reaching its lowest value (1  $\mu\text{A cm}^{-2}$ )  
606 in the 11.42 LiBr solution.

607

608 In the low and moderately concentrated LiBr solutions, a decrease of  $E_b$  with increasing  
609 bromide concentrations was observed, while in the more concentrated LiBr solutions,  $E_b$   
610 increased with increasing LiBr concentration. In the most concentrated LiBr solution  
611 (11.42M) Ti did not undergo passivity breakdown under the experimental conditions  
612 (up to 9  $\text{V}_{\text{Ag/AgCl}}$ ).

613

614 The steady-state passive current density,  $i_{SS}$ , was found to increase with  $\text{Br}^-$   
615 concentration at relatively low concentrations, but it decreased at high LiBr  
616 concentrations, following the same tendency as  $i_p$ .

617

618 The passive film formed on Ti behaved as an  $n$ -type semiconductor, with the dominant  
619 defects in the passive film being oxygen vacancies and/or  $\text{Ti}^{3+}$  interstitials. An increase  
620 in LiBr concentration from 0.1M to 0.5M led to a clear increase of the donor density  
621 ( $N_D$ ), but when increasing the LiBr concentration from 0.5M to 3M and 11.42M,  $N_D$   
622 decreased. However,  $N_D$  values obtained in concentrated LiBr solutions were still higher  
623 than in the 0.1M LiBr solution, so the electronic properties of  $\text{TiO}_2$  passive film could  
624 not be used to satisfactorily explain the increase of  $E_b$  at high LiBr concentrations or the  
625 absence of localized attacks in the 11.42M LiBr solution.

626

627 The resistance of the hydroxide outer layer of the passive film on Ti was higher in low  
628 concentrated LiBr solutions, whereas the resistance of the barrier layer of the film was  
629 found to be higher in concentrated LiBr solutions. These results could not be related to  
630 the degree of defectiveness of the passive film on Ti, but seemed to be associated with  
631 the passive film dissolution and the influence of the activity of water,  $a_w$ , on this  
632 process.

633

634 The activity of water,  $a_w$ , was found to have a strong influence on the susceptibility of  
635 Ti to undergo passivity breakdown. In view of the results, it may be concluded that a  
636 decrease in this parameter was responsible for the increase of the breakdown potential  
637 in highly concentrated LiBr solutions and water-methanol-LiBr mixtures. An empirical  
638 correlation between  $E_b$  and  $a_w$  was obtained for Ti in concentrated LiBr solutions.

639

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644

645

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763 **Tables**

764

765 **Table 1. Physical properties of the different LiBr solutions used in this work.**

$C_{LiBr}/mol\ l^{-1}$	$C_{LiBr}/g\ l^{-1}$	$m_{LiBr}/(mol\ LiBr)\ (kg\ H_2O)^{-1}$	$\gamma_{\pm}$	$a_{LiBr}$	$\phi$	$a_w$
0.05	4.34	0.05	0.93	0.05	0.95	1.00
0.10	8.68	0.10	0.80	0.08	0.94	1.00
0.30	26.05	0.31	0.76	0.23	0.95	0.99
0.50	43.42	0.51	0.75	0.39	0.97	0.98
0.70	60.79	0.72	0.77	0.56	1.00	0.97
1.15	100	1.20	0.84	1.01	1.07	0.95
3.00	260.52	3.77	1.75	6.60	1.53	0.81
4.61	400	5.69	3.56	20.26	1.93	0.67
8.06	700	11.18	21.89	222.82	2.95	0.34
11.42	992	15.15	154.00	2333.67	3.93	0.12

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767

768 **Table 2. Values of passive current density ( $i_p$ ) at 0.4 V and breakdown potential**769 **( $E_b$ ) of Ti in different LiBr solutions, obtained from potentiodynamic polarization**770 **curves.**

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$C_{LiBr}/mol\ l^{-1}$	$i_p/\mu A\ cm^{-2}$	$E_b\ vs\ (Ag/AgCl)/V$
0.05	$1.4 \pm 0.1$	$3.8 \pm 0.2$
0.10	$2.0 \pm 0.2$	$3.2 \pm 0.3$
0.30	$2.3 \pm 0.2$	$2.7 \pm 0.2$
0.50	$2.5 \pm 0.3$	$2.6 \pm 0.3$
0.70	$2.6 \pm 0.1$	$2.2 \pm 0.2$
1.15	$1.7 \pm 0.1$	$2.7 \pm 0.1$
3.00	$1.4 \pm 0.1$	$3.3 \pm 0.3$
4.61	$1.4 \pm 0.1$	$3.8 \pm 0.2$
8.06	$1.2 \pm 0.1$	$4.7 \pm 0.3$
11.42	$1.0 \pm 0.2$	-----

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785 **Table 3. Values of the equivalent circuit parameters for Ti in the 0.1M, 0.5M, 3M**  
 786 **and 11.42M LiBr solutions.**

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$C_{LiBr}/\text{mol l}^{-1}$	$R_S/\Omega$ $\text{cm}^2$	$R_1/\text{k}\Omega$ $\text{cm}^2$	$C_1/\mu\text{F}$ $\text{cm}^{-2}$	$\alpha_1$	$R_2/\text{k}\Omega$ $\text{cm}^2$	$C_2/\mu\text{F}$ $\text{cm}^{-2}$	$\alpha_2$	$\chi^2 (\times 10^{-3})$
0.1	$7 \pm 1$	$23 \pm 3$	$3.8 \pm 0.8$	$0.91 \pm 0.01$	$2391 \pm 157$	$4.6 \pm 0.5$	$0.78 \pm 0.24$	0.9
0.5	$4 \pm 0$	$28 \pm 2$	$4.4 \pm 0.7$	$0.90 \pm 0.01$	$1804 \pm 116$	$10.5 \pm 0.4$	$0.89 \pm 0.14$	1.8
3	$1 \pm 0$	$19 \pm 2$	$3.4 \pm 0.5$	$0.91 \pm 0.01$	$3144 \pm 108$	$1.3 \pm 0.3$	$0.94 \pm 0.09$	3.5
11.42	$2 \pm 0$	$16 \pm 2$	$3.2 \pm 0.6$	$0.94 \pm 0.01$	$3280 \pm 101$	$3.9 \pm 0.4$	$0.87 \pm 0.07$	4.1

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831 Tables captions

832

833 Table 1. Physical properties of the different LiBr solutions used in this work.

834

835 Table 2. Values of passive current density ( $i_p$ ) at 0.4 V and breakdown potential ( $E_b$ ) of Ti in different  
836 LiBr solutions, obtained from potentiodynamic polarization curves.

837

838 Table 3. Values of the equivalent circuit parameters for Ti in the 0.1M, 0.5M, 3M and 11.42M LiBr  
839 solutions.

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841 Figures captions

842

843 Fig. 1. Potentiodynamic polarization curves of Ti in different LiBr solutions at 25° C; (a) low and  
844 moderately concentrated LiBr solutions; (b) concentrated LiBr solutions.

845

846 Fig. 2. Images of the Ti electrode surface before and after the polarization tests in (a) 0.5M and (b)  
847 11.42M LiBr solutions.

848

849 Fig. 3. Plots of  $E_b$  vs.  $\log a_{Br^-}$  for Ti in the different LiBr solutions.

850

851 Fig. 4. Current density transients obtained after applying a potential step from a cathode value of -0.9 V  
852 to a passive value of 0.4 V for Ti in different LiBr solutions (0.1M, 0.5M, 3M and 11.42M).

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854 Fig. 5. Capacitance-potential curves obtained for Ti in 0.5M LiBr solution at 0.4 V and at different  
855 frequencies.

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857 Fig. 6. Mott-Schottky plots of the passive film formed on Ti in 0.1M, 0.5M, 3M and 11.42M LiBr  
858 solutions at 0.4 V, obtained at a frequency of 10 kHz.

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860 Fig. 7. Values of donor density ( $N_D$ ) of the passive film on Ti in different LiBr solutions (0.1M, 0.5M, 3M  
861 and 11.42M).

862 Fig. 8. Experimental and simulated Nyquist diagrams for Ti in 0.1M, 0.5M, 3M and 11.42M LiBr  
863 solutions at 0.4 V.

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865 Fig. 9. Electrical equivalent circuit used to fit the experimental EIS data.

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867 Fig. 10. Comparison of (a) mean ionic activity coefficients ( $\gamma_{\pm}$ ) and (b) activities of water ( $a_W$ ) between  
868 LiBr and KBr solutions.

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870 Fig. 11. Potentiodynamic polarization curves of Ti in a 0.5M LiBr solution with different water-methanol  
871 mol%.

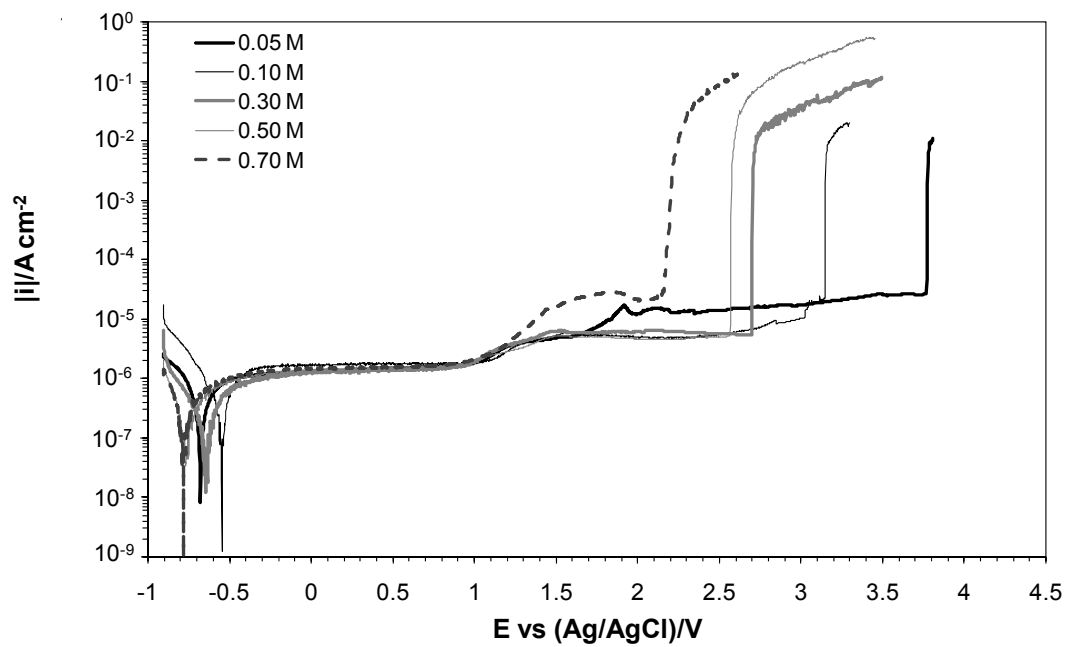
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873 Fig. 12. Potentiodynamic polarization curves of Ti in 3M KBr and 3M LiBr solutions.

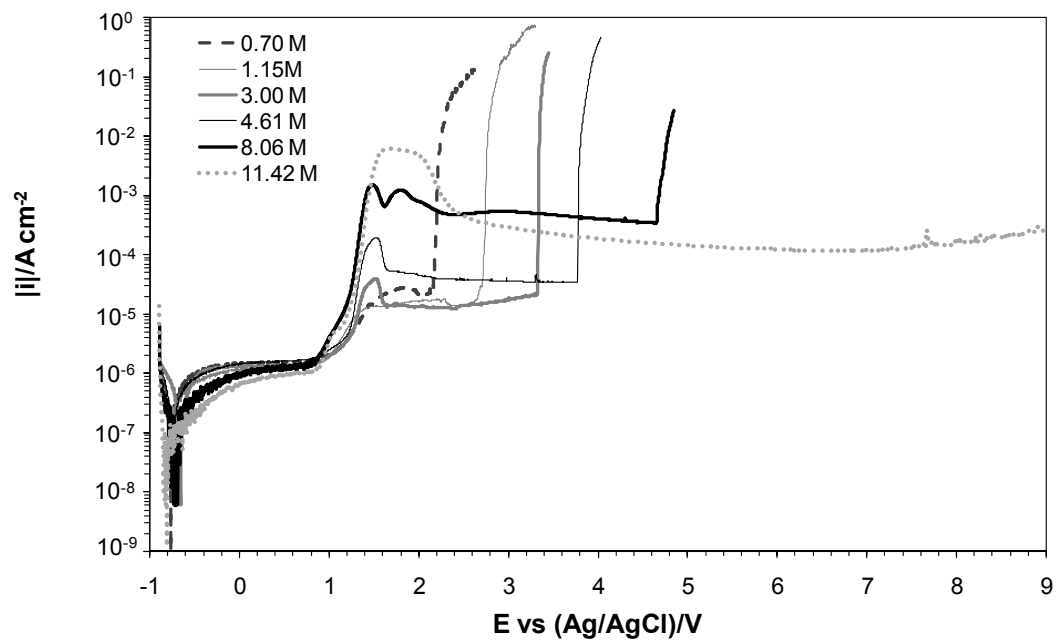
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875 Fig. 13. Experimental and calculated (using eq. (20)) values of  $E_b$  as a function of  $a_W$  in the highly  
876 concentrated LiBr solutions.

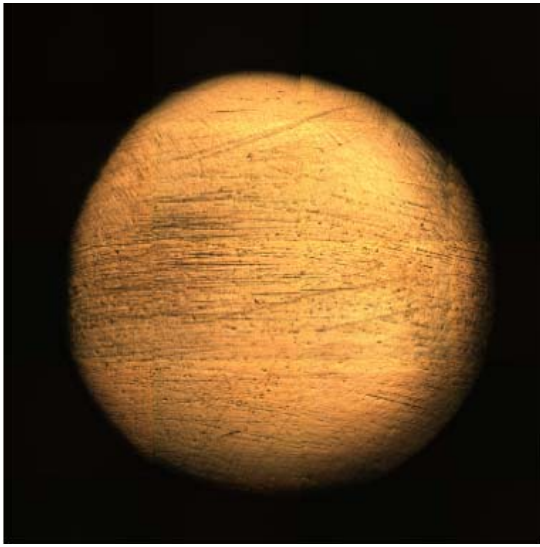
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(a)

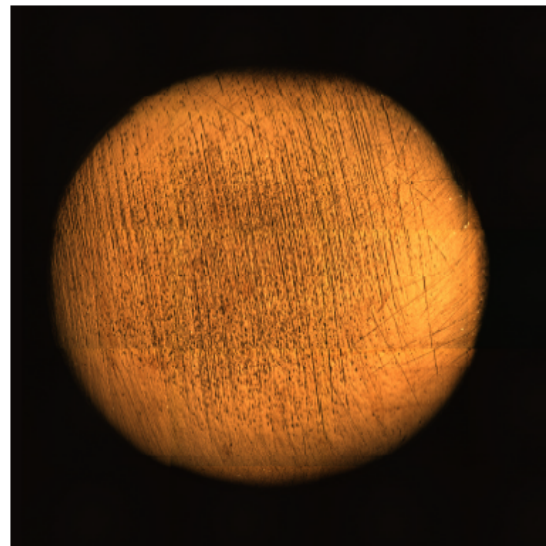
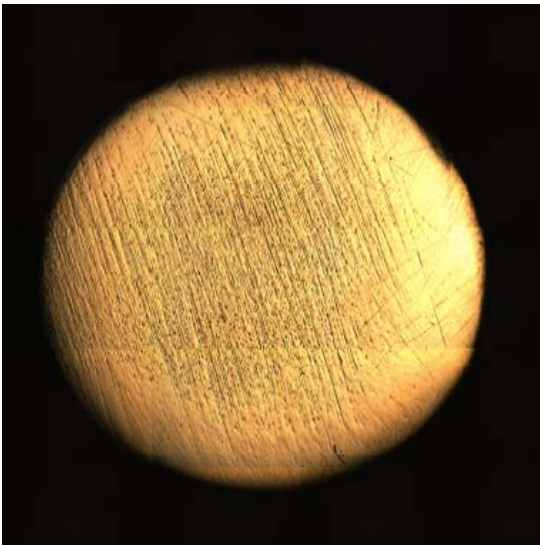


(b)



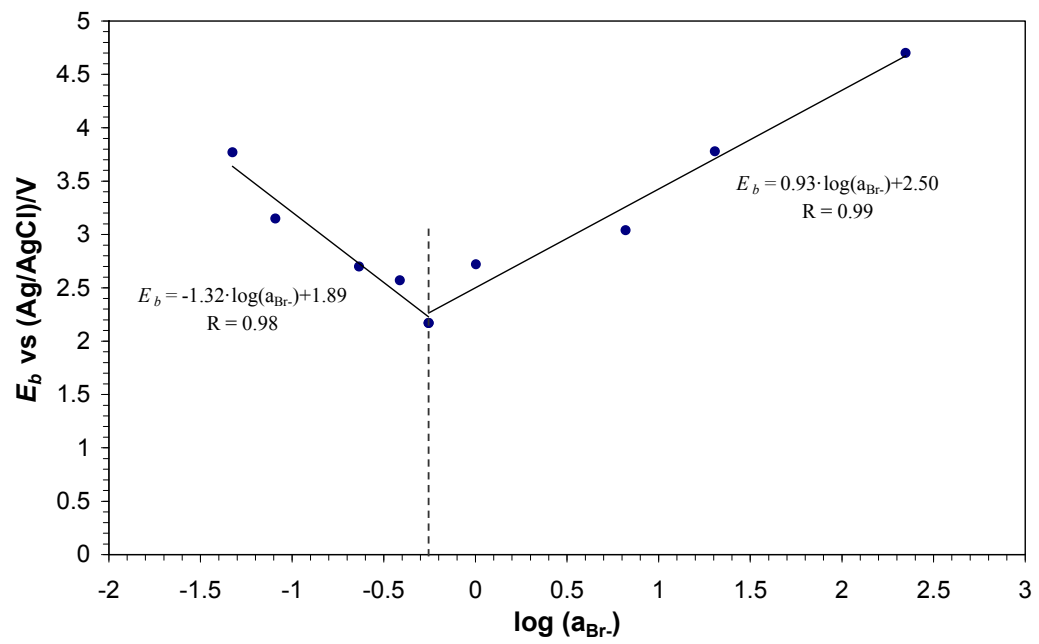
**Initial mosaic (sample diameter = 8 mm)      Final mosaic (sample diameter = 8 mm)**

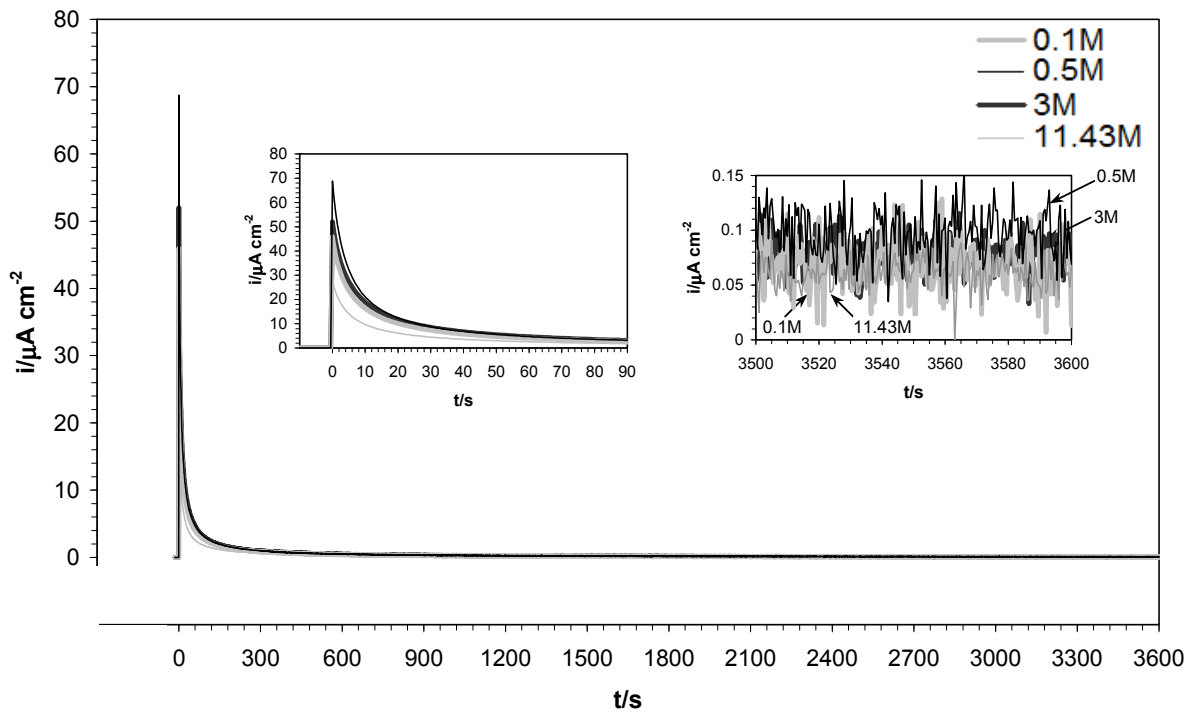
**(a)**

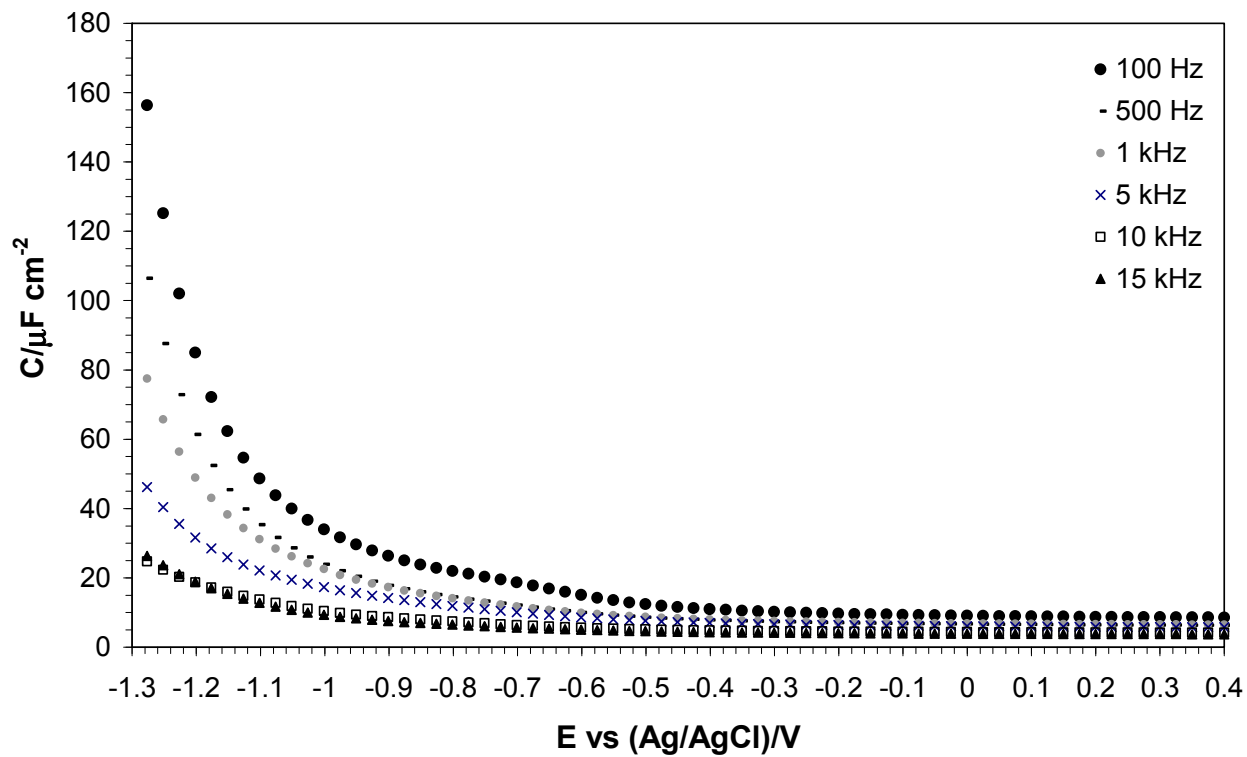


**Initial mosaic (sample diameter = 8 mm)      Final mosaic (sample diameter = 8 mm)**

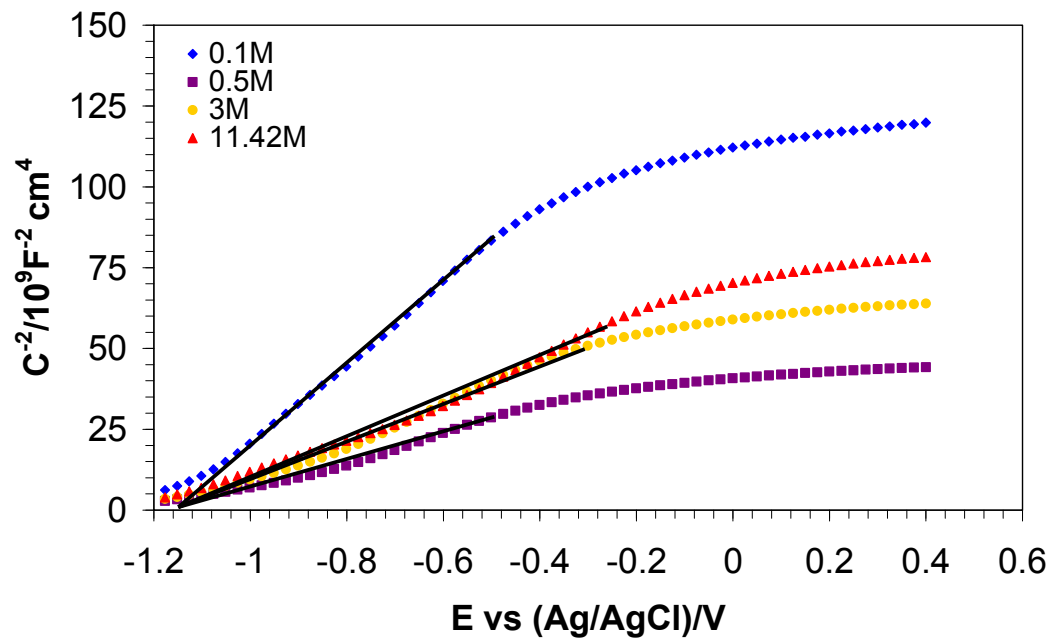
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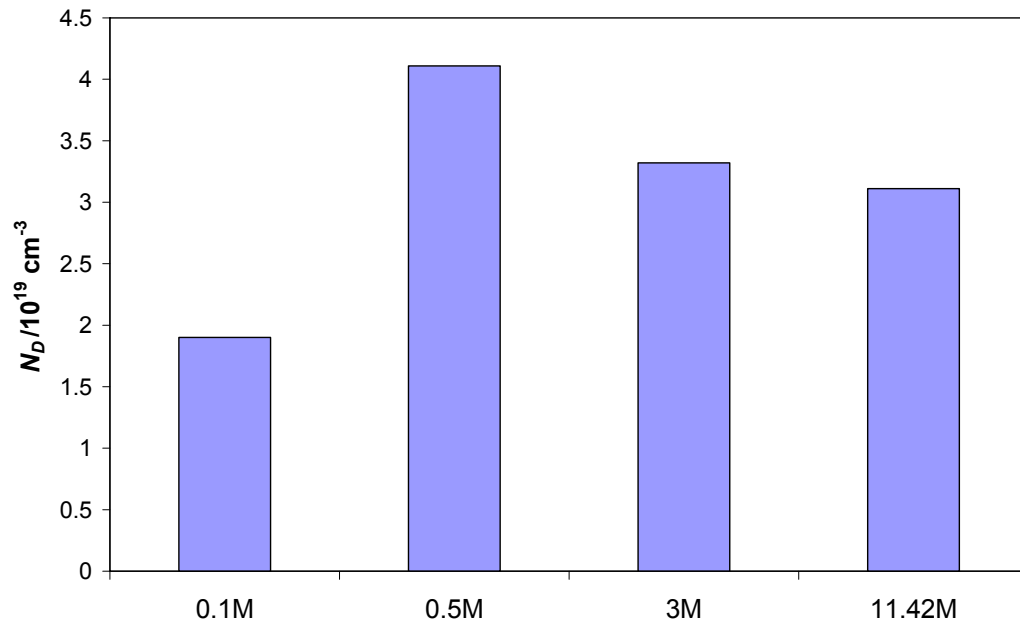


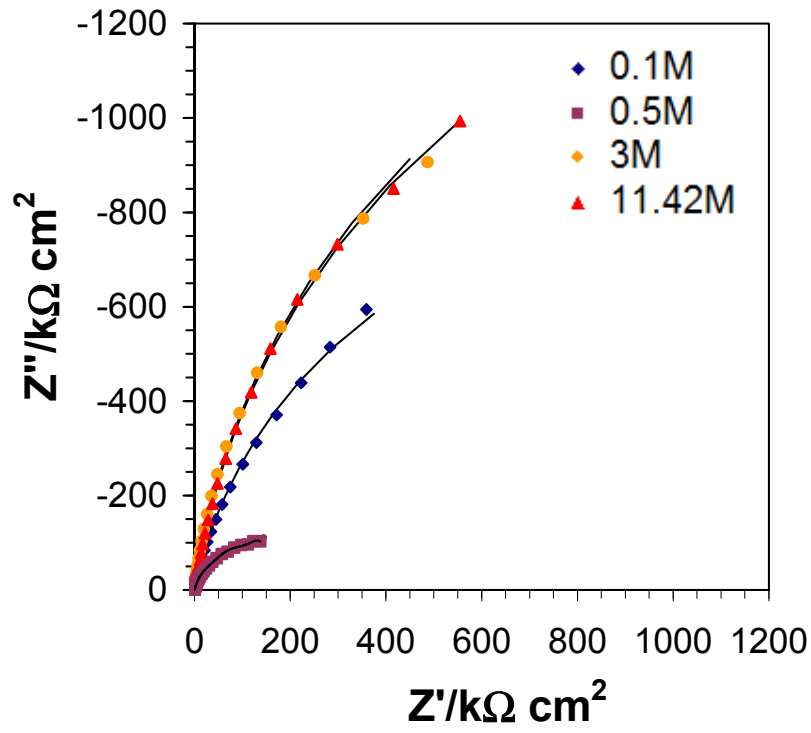


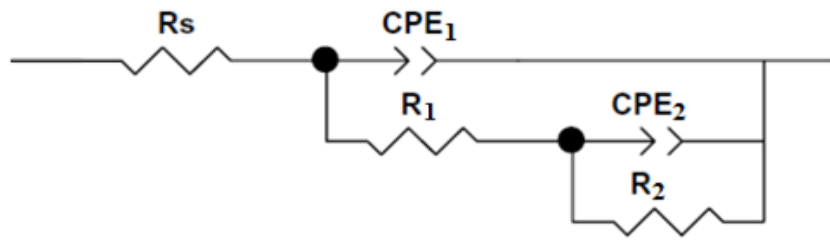


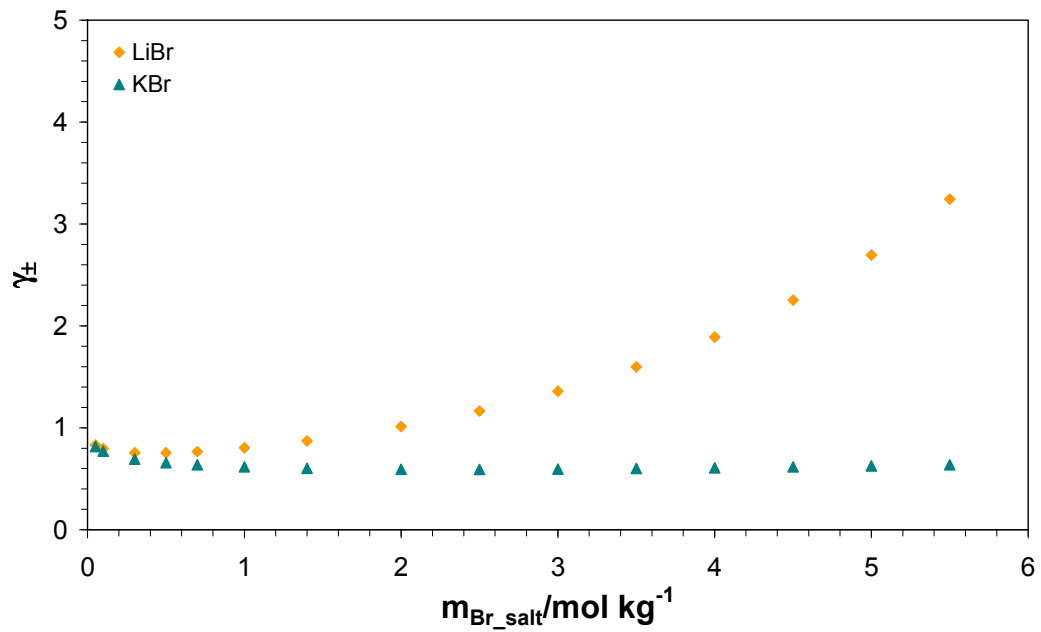




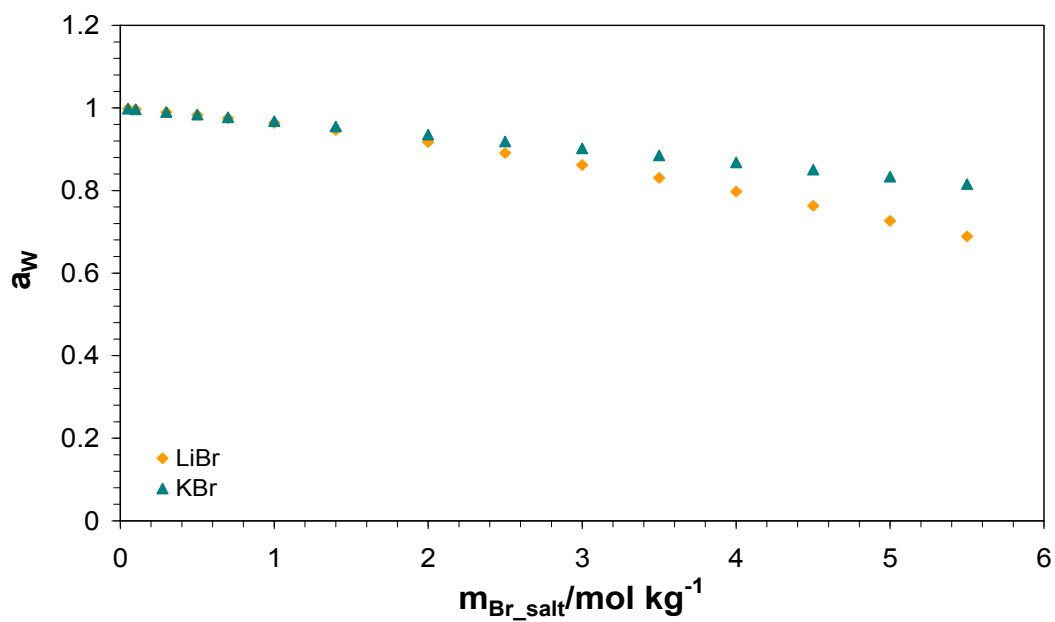








(a)



(b)

